Complementary ThermalTrak™ Transistors

The ThermalTrak family of devices has been designed to eliminate thermal equilibrium lag time and bias trimming in audio amplifier applications. They can also be used in other applications as transistor die protection devices.

Features

- Thermally Matched Bias Diode
- Instant Thermal Bias Tracking
- Absolute Thermal Integrity
- High Safe Operating Area
- Pb-Free Packages are Available*

Benefits

- Eliminates Thermal Equilibrium Lag Time and Bias Trimming
- Superior Sound Quality Through Improved Dynamic Temperature Response
- Significantly Improved Bias Stability
- Simplified Assembly
 - Reduced Labor Costs
 - Reduced Component Count
- High Reliability

Applications

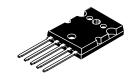
- High-End Consumer Audio Products
 - Home Amplifiers
 - Home Receivers
- Professional Audio Amplifiers
 - Theater and Stadium Sound Systems
 - Public Address Systems (PAs)



ON Semiconductor®

http://onsemi.com

BIPOLAR POWER TRANSISTORS 15 AMP, 260 VOLT, 200 WATT

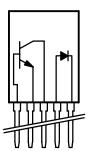


TO-264, 5 LEAD CASE 340AA STYLE 1

MARKING DIAGRAM

SCHEMATIC





NJLxxxxD = Device Code

xxxx = 3281 or 1302

G = Pb-Free Package A = Assembly Location

YY = Year

WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
NJL3281D	TO-264	25 Units / Rail
NJL3281DG	TO-264 (Pb-Free)	25 Units / Rail
NJL1302D	TO-264	25 Units / Rail
NJL1302DG	TO-264 (Pb-Free)	25 Units / Rail

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage	V _{CEO}	260	Vdc	
Collector-Base Voltage	V _{CBO}	260	Vdc	
Emitter-Base Voltage	V _{EBO}	5	Vdc	
Collector–Emitter Voltage – 1.5 V	V _{CEX}	260	Vdc	
Collector Current – Continuous – Peak (Note 1)	Ic	15 25	Adc	
Base Current – Continuous	Ι _Β	1.5	Adc	
Total Power Dissipation @ T _C = 25°C Derate Above 25°C	P _D	200 1.43	W W/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	- 65 to +150	°C	
DC Blocking Voltage	V _R	200	V	
Average Rectified Forward Current	I _{F(AV)}	1.0	Α	

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	0.625	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ATTRIBUTES

Chara	Value		
ESD Protection	Human Body Model Machine Model	>8000 V > 400 V	
Flammability Rating		UL 94 V-0 @ 0.125 in	

^{1.} Pulse Test: Pulse Width = 5 ms, Duty Cycle < 10%.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	•		•	•
Collector–Emitter Sustaining Voltage $(I_C = 100 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	260	_	Vdc
Collector Cutoff Current (V _{CB} = 260 Vdc, I _E = 0)	I _{CBO}	-	50	μAdc
Emitter Cutoff Current (V _{EB} = 5 Vdc, I _C = 0)	I _{EBO}	-	5	μAdc
ON CHARACTERISTICS	-		•	•
DC Current Gain $ \begin{array}{l} (I_C = 500 \text{ mAdc, } V_{CE} = 5 \text{ Vdc)} \\ (I_C = 1 \text{ Adc, } V_{CE} = 5 \text{ Vdc)} \\ (I_C = 3 \text{ Adc, } V_{CE} = 5 \text{ Vdc)} \\ (I_C = 5 \text{ Adc, } V_{CE} = 5 \text{ Vdc)} \\ (I_C = 8 \text{ Adc, } V_{CE} = 5 \text{ Vdc)} \\ (I_C = 8 \text{ Adc, } V_{CE} = 5 \text{ Vdc)} \end{array} $	h _{FE}	75 75 75 75 75 45	150 150 150 150 150	
Collector–Emitter Saturation Voltage (I _C = 10 Adc, I _B = 1 Adc)	V _{CE(sat)}	_	3	Vdc
DYNAMIC CHARACTERISTICS	-		•	•
Current-Gain - Bandwidth Product (I _C = 1 Adc, V _{CE} = 5 Vdc, f _{test} = 1 MHz)	f _T	30	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f _{test} = 1 MHz)	C _{ob}	-	600	pF
Maximum Instantaneous Forward Voltage (Note 2) ($i_F = 1.0 \text{ A}, T_J = 25^{\circ}\text{C}$) ($i_F = 1.0 \text{ A}, T_J = 150^{\circ}\text{C}$)	VF	1.1 0.93		V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, T _J = 25°C) (Rated dc Voltage, T _J = 150°C)	i _R		0 00	μΑ
Maximum Reverse Recovery Time (i _F = 1.0 A, di/dt = 50 A/μs)	t _{rr}	10	00	ns

Diode Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

TYPICAL CHARACTERISTICS

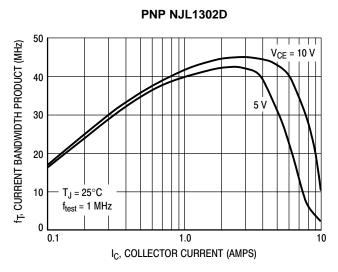


Figure 1. Typical Current Gain Bandwidth Product

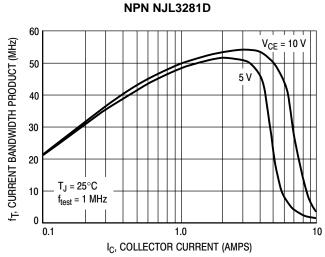


Figure 2. Typical Current Gain Bandwidth Product

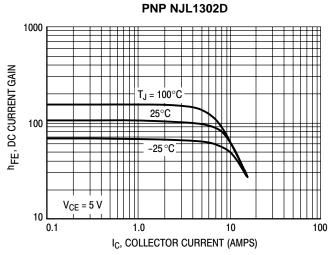


Figure 3. DC Current Gain, V_{CE} = 5 V

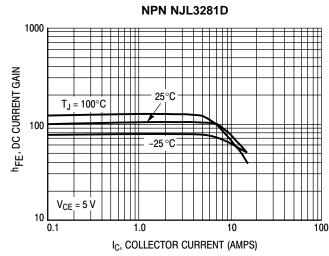


Figure 4. DC Current Gain, V_{CE} = 5 V

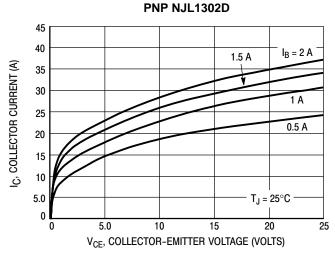


Figure 5. Typical Output Characteristics

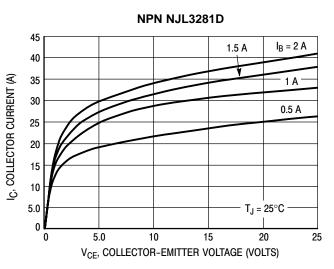


Figure 6. Typical Output Characteristics

TYPICAL CHARACTERISTICS

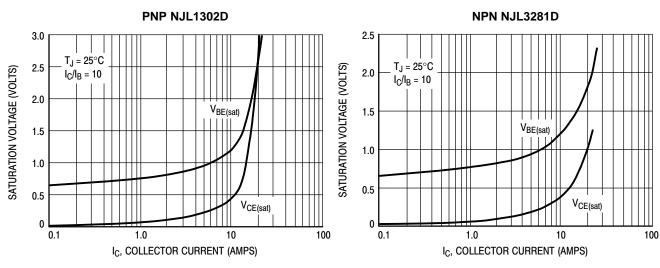


Figure 7. Typical Saturation Voltages

Figure 8. Typical Saturation Voltages

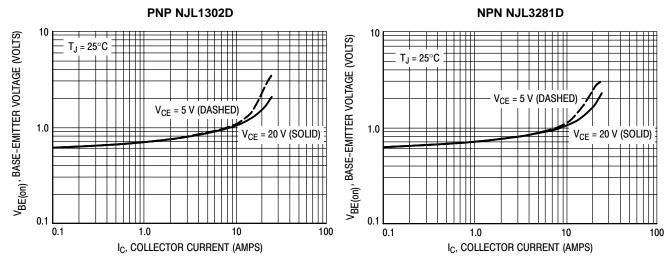


Figure 9. Typical Base-Emitter Voltage

Figure 10. Typical Base-Emitter Voltage

TYPICAL CHARACTERISTICS

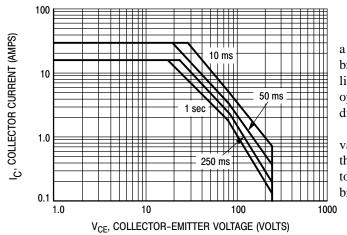


Figure 11. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 11 is based on $T_{J(pk)} = 150$ °C; T_{C} is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

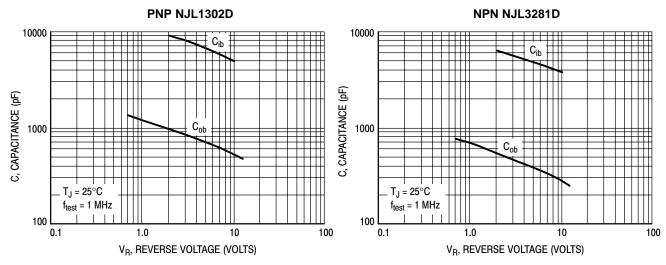


Figure 12. NJL1302D Typical Capacitance

Figure 13. NJL3281D Typical Capacitance

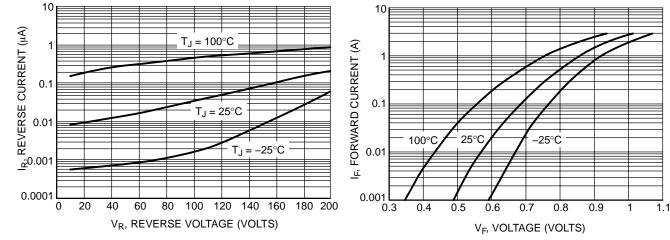


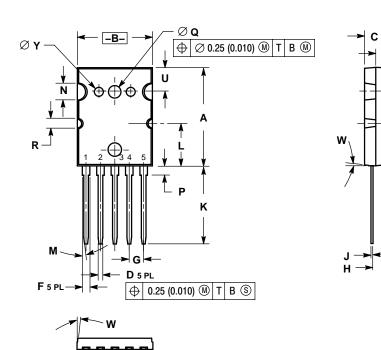
Figure 14. Typical Reverse Current

Figure 15. Typical Forward Voltage

PACKAGE DIMENSIONS

TO-264, 5 LEAD CASE 340AA-01 **ISSUE O**

-T-





- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	25.857	25.984	26.111	1.018	1.023	1.028
В	19.761	19.888	20.015	0.778	0.783	0.788
С	4.928	5.055	5.182	0.194	0.199	0.204
D	1.	219 BS0	0	0.	0480 BS	SC
Е	2.032	2.108	2.184	0.0800	0.0830	0.0860
F	1.	981 BS	2	0.	0780 BS	SC
G	3	3.81 BSC		0	.150 BS	С
Н	2.667	2.718	2.769	0.1050	0.1070	0.1090
J	C	0.584 BSC		0.0230 BSC		SC
K	20.422	20.549	20.676	0.804	0.809	0.814
L	1	11.28 REF		0.444 REF		F
M	0 °		7 °	0 °		7 °
N		4.57 RE	F	0.180 REF		EF
Р	2.259	2.386	2.513	0.0889	0.0939	0.0989
Q		3.480 BSC		0.1370 BSC		SC
R		2.54 REF		0.100 REF		
S	0 °		8 °	0 °		8 °
U		6.17 REF		0.243 REF		
W	0 °		6 °	0 °		6°
Υ		2.388 B	SC	0.0940 BSC		

STYLE 1:

PIN 1. BASE 2. EMITTER

- 3. COLLECTOR 4. ANODE
- 5. CATHODE

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